#### **Philips Semiconductors**

# Dual rectifier diodes ultrafast

### **Product specification**

# **BYV44 series**

QUICK REFERENCE DATA

 $V_{R} = 300 \text{ V} / 400 \text{ V} / 500 \text{ V}$ 

 $V_F \leq 1.12 \text{ V}$ 

 $I_{O(AV)} = 30 \text{ A}$ 

 $t_{rr} \leq 60 \text{ ns}$ 

# FEATURES

- Low forward volt drop
- Fast switching

supplies.

conventional

- Soft recovery characteristic
- High thermal cycling performance

**GENERAL DESCRIPTION** 

Dual, common cathode, ultra-fast,

epitaxial rectifier diodes intended

for use as output rectifiers in high

frequency switched mode power

The BYV44 series is supplied in the

leaded

• Low thermal resistance



# PINNING

PIN

1

2

3

tab

anode 1

cathode

anode 2

cathode

# DESCRIPTION



### LIMITING VALUES

(TO220AB) package.

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SOT78

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage	<b>BYV44</b> T <sub>mb</sub> ≤ 136°C	- - -	<b>-300</b> 300 300 300	<b>-400</b> 400 400 400	<b>-500</b> 500 500 500	< < <
I <sub>O(AV)</sub> I <sub>FRM</sub>	Average rectified output current (both diodes conducting) <sup>1</sup> Repetitive peak forward current per diode	T <sub>mb</sub> ≤ 94 °C	-		30 30		A A
I <sub>FSM</sub>	Non-repetitive peak forward current per diode.	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		150 160		A A
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature	V <sub>RRM(max)</sub>	-40 -		150 150		Ĵ Ĵ

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	heatsink	per diode both diodes conducting in free air.		- - 60	2.4 1.4 -	K/W K/W K/W

<sup>1</sup> Neglecting switching and reverse current losses.

For output currents in excess of 20 A, the cathode connection should be made to the metal mounting tab.

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# ELECTRICAL CHARACTERISTICS

characteristics are per diode at  $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	$I_F = 15 \text{ A}; T_j = 150^{\circ}\text{C}$	-	0.95	1.12	V
		I <sub>F</sub> = 15 A	-	1.08	1.25	V
		$I_{\rm F} = 30  {\rm A}$	-	1.15	1.36	V
I <sub>R</sub>	Reverse current	$V_{R} = V_{RRM}$	-	10	50	μA
		$V_{P} = V_{PPM}$ ; T <sub>i</sub> = 100 °C	-	0.3	0.8	mΑ
Q <sub>s</sub>	Reverse recovery charge	$ I_{\rm F} = 2 \text{ A to } V_{\rm R}^{\prime} \ge 30 \text{ V};$	-	40	60	nC
		$dI_F/dt = 20 A/\mu s$				
t <sub>rr</sub>	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	50	60	ns
		$dI_F/dt = 100 A/\mu s$				
I <sub>rrm</sub>	Peak reverse recovery current	$I_F = 10 \text{ A to } V_R \ge 30 \text{ V};$ $dI_F/dt = 50 \text{ A/}\mu\text{s}; T_i = 100^{\circ}\text{C}$	-	4.2	5.2	А
		dI <sub>F</sub> /dt = 50 A/μs; T <sub>i</sub> = 100°C				
V <sub>fr</sub>	Forward recovery voltage	$I_{F} = 10 \text{ A}; \text{ d}I_{F}/\text{d}t = 10 \text{ A}/\mu\text{s}$	-	2.5	-	V









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# **MECHANICAL DATA**



**Notes** 1. Refer to mounting instructions for SOT78 (TO220) envelopes. 2. Epoxy meets UL94 V0 at 1/8".

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# DEFINITIONS

Data sheet status				
Objective specification	Dbjective specificationThis data sheet contains target or goal specifications for product development.			
Preliminary specification	reliminary specification This data sheet contains preliminary data; supplementary data may be published late			
Product specification	pecification This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
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